

WHAT IS CLAIMED IS:

1. A semiconductor device comprising:

a translucent substrate;

a base film having a region of a first thickness and a region of a second thickness smaller

5 than the first thickness, the film being formed over one surface of the translucent substrate, and
the region of the first thickness having an area smaller than the region of the second thickness;
and

an island-like semiconductor layer having a crystal structure over the base film, the layer
being formed over the region of the first thickness and the region of the second thickness.